









	HGTG10N120BND	
	Hersteller-Teilenummer:	HGTG10N120BND
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	IGBT 1200V 35A 298W TO247
	Datenblätter:	 HGTG10N120BND.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 7756 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	HGTG10N120BND
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 1200V 35A 298W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	7756 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	298W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Rückwärts-Erholzeit (Trr)	70ns
Strom - Kollektor (Ic) (max)	35A
Spannung - Kollektor-Emitter-Durchbruch (max)	1200V
IGBT-Typ	NPT
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 10A
Strom - Collector Pulsed (Icm)	80A
Schaltenergie	850µJ (on), 800µJ (off)
Gate-Ladung	100nC
Td (ein / aus) bei 25 ° C	23ns/165ns
Testbedingung	960V, 10A, 10 Ohm, 15V
Verpackung	Tube

















































HGTG10N120BND ist neu im Original, Suche HGTG10N120BND Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTG10N120BND Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTG10N120BND: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>HGTD8P50G1 HARRIS HARRIS TO-251</p>	 <p>HGTG11N120CND AMI Semiconductor / ON Semiconductor IGBT 1200V 43A 298W TO247</p>	 <p>HGTG11N120CN Fairchild/ON Semiconductor IGBT 1200V 43A 298W TO247</p>	 <p>HGTD7N60C3S9A Fairchild/ON Semiconductor IGBT 600V 14A 60W TO252AA</p>
 <p>HGTD7N60C3S HARRIS HARRIS TO-252</p>	 <p>HGTG10N120BN Fairchild/ON Semiconductor HGTG10N120BN FAIRCHILD</p>	 <p>HGTG11N120CN AMI Semiconductor / ON Semiconductor IGBT 1200V 43A 298W TO247</p>	 <p>HGTD7N60C3S9A AMI Semiconductor / ON Semiconductor IGBT 600V 14A 60W TO252AA</p>

heiße Teile

Mehr

 HGT1S20N36G3VLSR4737	 HGT1S20N60A4S9A	 HGT1S20N60A4S9A	 HGT1S20N60C3R	 HGT1S20N60C3RS
 HGT1S2N120CN	 HGT1S2N120CN	 HGT1S3N60A4DS	 HGT1S3N60A4DS9A	 HGT1S3N60A4DS9A
 HGT1S3N60B3DS	 HGT1S3N60C3DS9A	 HGT1S7N60A4DS	 HGT1S7N60A4DS	 HGT1S7N60A4DS.G7N60A4D
 HGT1S7N60A4DS9A	 HGT1S7N60A4S9A	 HGT1S7N60B3	 HGT1S7N60B3DS	 HGT1S7N60B3S
 HGT1S7N60C3DS9A	 HGT1S7N60C3DS9A	 HGTD1N120BNS9A	 HGTD1N120BNS9A	 HGTG10N120BND
 HGTG11N120CN	 HGTG11N120CN	 HGTG11N120CND	 HGTG11N120CND	 HGTG12N60A4
 HGTG12N60A4	 HGTG12N60A4D	 HGTG12N60A4D	 HGTG12N60B3D	 HGTG12N60C3D
 HGTG12N60C3D	 HGTG18N120BN	 HGTG18N120BN	 HGTG18N120BND	 HGTG18N120BND
 HGTG20N120CND	 HGTG20N120E2	 HGTG20N50C1D	 HGTG20N60	 HGTG20N60A4
 HGTG20N60A4	 HGTG20N60A4D	 HGTG20N60A4D	 HGTG20N60B3	 HGTG20N60B3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited